



TO-5 RELAYS ESTABLISHED RELIABILITY MILITARY DPDT



SERIES	RELAY TYPE
432	DPDT basic relay
432D	DPDT relay with internal diode for coil transient suppression
432DD	DPDT relay with polarity reversal protection and coil transient suppression diode
432T	DPDT relay with internal transistor driver and coil transient suppression diode

DESCRIPTION

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed expressly for high-density PC board mounting, its small size and low coil power dissipation make the 432 relay one of the most versatile ultraminiature relays available.

The following unique construction features and manufacturing techniques provide excellent resistance to environmental extremes and overall high reliability.

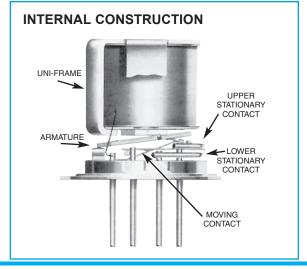
The 432 feature:

- · All welded construction.
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity.
- · High force/mass ratios for resistance to shock and vibration.
- Advanced cleaning techniques provide maximum assurance of internal cleanliness
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities.

The Series 432D and 432DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid 432T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

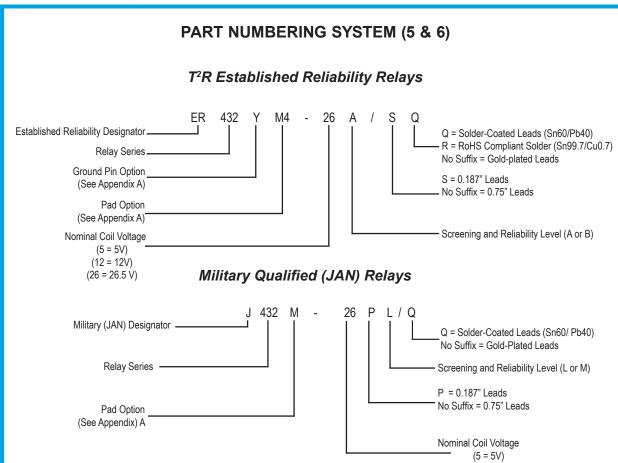
By virtue of its inherently low intercontact capacitance and contact circuit losses, the 432 relay has shown its worth as an RF switch for frequency ranges well into the UHF spectrum (see Figure 1). In addition, the sensitive Series 432 relay has a high resistance coil, thus requiring extremely low operating power (200 milliwatts, typical at room temperature). The advantages of reduced heat dissipation and power supply demands are a plus.

ENVIRONMENTAL AND PHYSICAL SPECIFICATIONS			
Temperature (Ambient)	−65°C to +125°C		
Vibration (Note 1)	30 g's to 3000 Hz		
Shock (Note 1)	75 g's, 6ms half sine		
Acceleration	50 g's		
Enclosure	Hermetically sealed		
Weight	0.159 oz. (4.5g) max.		
Reflow Temperature	260°C max. temp. 1 min. max		



(12 = 12V)(26 = 26.5 V)



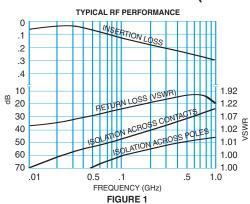


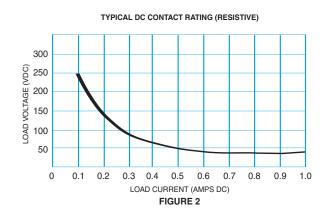


GENERAL ELECTRICAL SPECIFICATIONS (-65°C to +125°C unless otherwise noted) (Notes 2 &3)

Contact Arrangement	2 Form C (DPDT)			
Rated Duty	Continuous			
Contact Resistance	0.1 ohm max. before life; 0.2 ohm max. after life at 1A/28Vdc (measured 1/8" from header)			
Contact Load Rating (DC)	Resistive: 1 A/ 28 Vdc Inductive: 200 mA/ 28 Vdc (320mH) Lamp: 100 mA / 28 Vdc (320mH) Low level: 10 to 50 µA @ 10 to 50 mV			
Contact Load Rating (AC)	Resistive: 250 mA / 115Vac, 60 and 400 Hz (Case not grounded) 100 mA / 115 Vac, 60 and 400 Hz (Case grounded)			
Contact Life Ratings	10,000,000 cycles (typical) at low level 1,000,000 cycles (typical) at 0.5 A / 28 V _{dc} resistive 100,000 cycles min. at all other loads specified above			
Contact Overload Rating	2 A / 28 Vdc Resistive (100 cycles min.)			
Coil Operating Power	200 mW typical at nominal rated voltage			
Contact Carry Rating	Contact Factory			
Operate Time	4.0 ms max. at nominal rated coil voltage			
Release Time	432: 1.5 ms max. 432D, 432DD, 432T: 7.5 ms m	nax		
Contact Bounce	1.5 ms max			
Intercontact Capacitance	0.4 pf typical			
Insulation Resistance	10,000 M Ω min. between mutually isolated terminals	Ω min. between mutually isolated terminals		
Dialactuia Otaca ath	500 V _{rms} / 60 Hz @ atmospheric pressure			
Dielectric Strength	125 V _{rms} / 60 Hz @ 70,000 ft			
Negative Coil Transient (Vdc) 432D, 432DD, 432T	mo			
Diode P.I.V. (Vdc) 432D, 432DD, 432T	100 Vdc Min.			
	Base Voltage to Turn Off (Vdc)	0.3 min		
432T Transistor Characteristics	Emitter-Base breakdown Voltage (BV _{EBO}) (@25°C) (Vdc) 6.0 min			
3.0.00	Collector-Base breakdown Voltage (BV $_{CBO}$) (@25°C & Ic = 100 μ A) (Vdc)	75 min		

PERFORMANCE CURVES (Note 2)







DETAILED ELECTRICAL SPECIFICATIONS (-65°C to +125°C unless otherwise noted) (Notes 3)

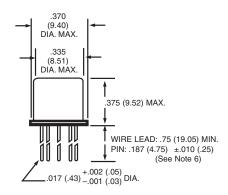
BASE PART NUMBERS (432, 432D, 432DD, 432T)		432-5 432D-5 432DD-5 432T-5	432-12 432D-12 432DD-12 432T-12	432-26 432D-26 432DD-26 432T-26	
Coil Voltage	Nom.		5.0	12.0	26.5
Coil Voltage	Max.		5.8	16.0	32.0
Coil Resistance	432, 432D, 432T (Note 4)		100	850	3300
(Ohms ±10% @25°C)	432DD (Note 4)		64	850	3300
Coil Curent (432DD)	Min		56.8	11.7	7.0
(mAdc@25°C)	Max		78.1	15.0	8.8
Coil Curent (432T) (mAdc@25°C)	Min		43.5	12.2	6.9
(IIIAuc@25 C)	Max		59.3	16.7	9.5
	432, 432D		3.5	9.0	18.0
Pick-up Voltage (Vdc, Max)	432DD		3.7	11.0	19.0
	432T		3.6	11.0	19.0
	432, 432D, 432T	Min.	0.14	0.41	0.89
Drop-out Voltage		Max.	2.5	6.5	13.0
(Vdc)	432DD	Min.	0.7	1.0	1.3
		Max.	2.6	5.8	13.0
Turn On Base Current 432T (mA Max), (Note 7)		1.50	0.47	0.24	

NOTES

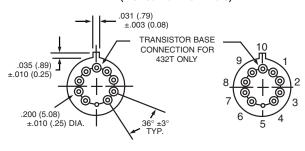
- 1. Relay contacts will exhibit no chatter in excess of 10 μs or transfer in excess of 1 μs .
- 2. "Typical" characteristics are based on available data and are best estimates. No on-going verification tests are performed.
- 3. Unless otherwise specified, parameters are initial values.
- 4. Reference only for 432DD and 432T. Coil resistance not directly measurable at relay terminals due to internal series semiconductor.
- 5. Unless otherwise specified, relays will be supplied with gold-plated leads.
- 6. The slash and characters appearing after the slash are not marked on the relay.
- 7. Limit Base Emitter current to 15 $\mathrm{mA}_{\mathrm{dc}}$ max.



SERIES 432 OUTLINE DIMENSIONS

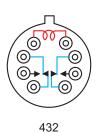


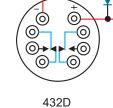
TERMINAL LOCATIONS AND PIN NUMBERING (REF. ONLY) (Viewed from Terminals)

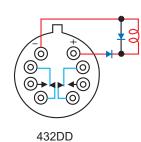


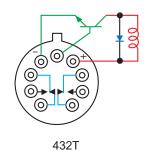
DIMENSIONS ARE SHOWN IN INCHES (MILLIMETERS)

SCHEMATIC DIAGRAMS



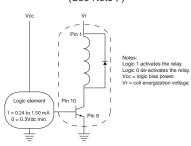






TYPICAL LOGIC INTERFACE

(See Note 7)





APPENDIX A: Spacer Pads, Spreader Pads, and Ground Pin Positions

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
"M4" Spacer Pad for TO-5	Dim H MAX	ER432, J432	.400 (10.16)

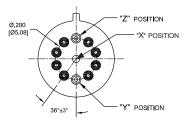
Notes:

- 1. Spacer pad material: Polyester film.
- 2. To specify an "M4" spacer pad, refer to the mounting variants portion of the part numbering example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (.25 mm).
- 5. Add 10 m Ω to the contact resistance shown in the datasheet.
- 6. Add 0.01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
.370 [9.4] MAX SQ .100 [2.54] .300 [7.62]	Dim H MAX .014 (0.36) (REF) .370 [9.4] MIN	ER432, J432	.493 (12.52)

Notes

- 1. Spreader pad material: Diallyl Phthalate.
- To specify an "M" spreader pad, refer to the mounting variants portion of the part number example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (0.25 mm).
- $\underline{5}/.$ Add 25 $m\Omega$ to the contact resistance shown in the datasheet.
- 6/. Add .01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.



TO-5 Relays:

FR412, ER412T, ER422, ER432, ER432T, 712, 712TN, 400H, 400K, 400V, RF300, RF303, RF312, RF332, RF700, RF703

- O Indicates ground pin position
- ndicates glass insulated lead position
- Indicates ground pin or lead position depending on relay type

NOTES

- 1. Terminal views shown
- 2. Dimensions are in inches (mm)
- 3. Tolerances: ± .010 (±.25) unless otherwise specified
- 4. Ground pin positions are within .015 (0.38) dia. of true position
- 5. Ground pin head dia., 0.035 (0.89) ref: height 0.010 (0.25) ref.
- 6. Lead dia. 0.017 (0.43) nom.
- 7. "X" and "Z" Positions are not applicable for JAN Relays